

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18 Stylesheet Version v18.0

Title of Invention

METHOD FOR CONTROLLING A PROCESS FOR FABRICATING INTEGRATED DEVICES

Application Number:

10/805136

Confirmation Number:

8916

First Named Applicant: Matthew Davis
Attorney Docket Number: 8381/ETCH

Search string:

(6566025).pn.

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
MA	1	6566025	2003-05-20	McStravick et al.	B1		

Signature

Examiner Name	Date		
/Maki Angadi/	11/08/2006		

Sheet 1 of 1 sheet(s)

U.S. Department of Commerce, Patent and Trademark Office					Docket No. Serial No.				
(PTO Form 1449 modified)					8381/ETCH/SILICON/JB1		10/805,136		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT						Applicant Confirmation Davis, et al. No.: 8916			
(Use severa	al shee	ets if necessary)	Filing Date		Group				
Examiner Examiner						March 19, 2004			
U.S. Patent	Docu	ıments	Ze TRADE STATE						
*Examiner Initial		Document Number	Issue Date	Applicant(s) Name	Class	Subclass	Filing Date If Appropriate		
	A1	4,767,496	08/30/1988	Hieber	156	627			
	A2	5,798,529	08/25/1998	Wagner	250	492.2			
	А3	5,926,690	07/20/1999	Toprac et al.	438	17			
<u> </u>	A4	5,948,203	09/07/1999	Wang	156	345			
	A5	6,004,706	12/21/1999	Ausschnitt et al.	430	30			
	A6	6,027,842	02/22/2000	Ausschnitt et al.	430	30			
	A7	6,161,054	12/12/2000	Rosenthal et al.	700	121			
	A8	6,245,581	06/12/2001	Bonser et al.	438	8			
	A9	6,424,417	07/23/2002	Cohen et al.	356	388			
	A10	6,486,492	11/26/2002	Su	257	48			
√ ма	A11	2002/0171828	11/21/2002	Cohen et al.	356	328	07/01/2002	?	
Foreign Pa	tent D	Documents							
*Examiner	Document		Date	Country	Class	Subclass	Translation		
Initial		Number					YES	NO	
	B1								
	B2								
OTHER AR	₹T	**							
*Examiner Initial	xaminer Including Author, Title, Date, Pertinent Pages, Etc.								
MA	C1	Lee, et al., "Analysis of Reflectometry and Ellipsometry Data from Patterned Structures," Characterization and Metrology for UCSI Technology: 1998 International Conference, Seiler, et al., eds., pg 331-335							
MA	C2	World, Winter 2000.							
MA	СЗ	Toprac, A., "AMD's Advanced Process Control of Ply-Gate Critical Dimension," Proc. SPIE Vol. 3882, pg 62-65, Sept, 1999.							
MA	C4	Yang, et al., "Line-profile and Critical Dimension Measurements Using a Normal Incidence Optical Metrology System," Proceedings of SPIE Vol. 4689, March 2002,							
Examiner	/Maki Angadi/				Date Considered 11/08/2006				
+5×4+4×155	l laitial	I if reference consider	rod whether or r	not citation is in confi	ormance wi	th MPEP 609	: Draw line thr	ough	